



SANYO Semiconductors

DATA SHEET

CPH3144 / CPH3244

PNP / NPN Epitaxial Planar Silicon Transistors

DC / DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, flash.

Features

- Adoption of MBIT process.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm).
- High allowable power dissipation.

Specifications () : CPH3144

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-30)40	V
Collector-to-Emitter Voltage	V _{CEO}		(-)30	V
Emitter-to-Base Voltage	V _{EB0}		(-)5	V
Collector Current	I _C		(-)2	A
Collector Current (Pulse)	I _{CP}		(-)5	A
Base Current	I _B		(-)400	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)30V, I _E =0			(-)0.1	μA
Emitter Cutoff Current	I _{EB0}	V _{EB} =(-)4V, I _C =0			(-)0.1	μA
DC Current Gain	h _{FE}	V _{CE} =(-)2V, I _C =(-)100mA	200		560	
Gain-Bandwidth Product	f _T	V _{CE} =(-)10V, I _C =(-)300mA		(440)400		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(17)12		pF

Marking : CPH3144 : BD, CPH3244 : DP

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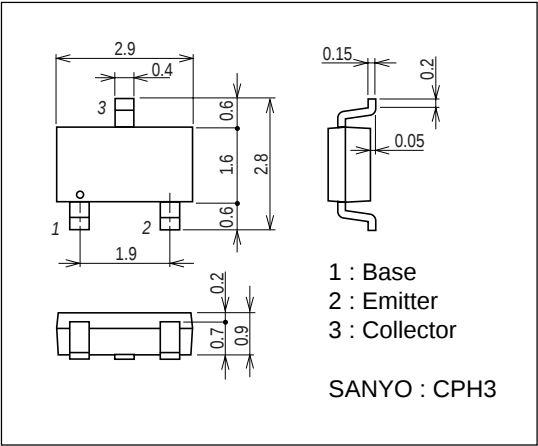
CPH3144 / CPH3244

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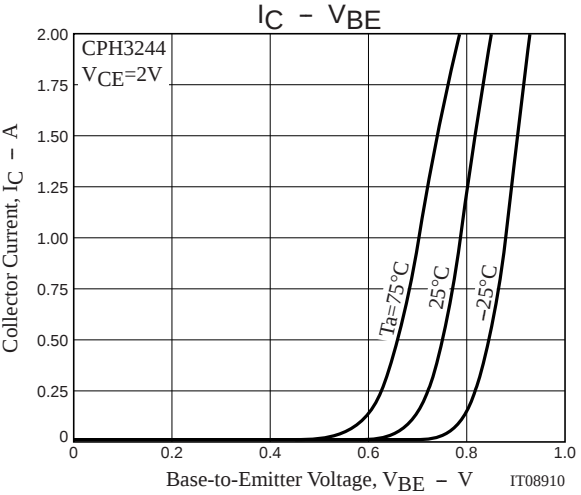
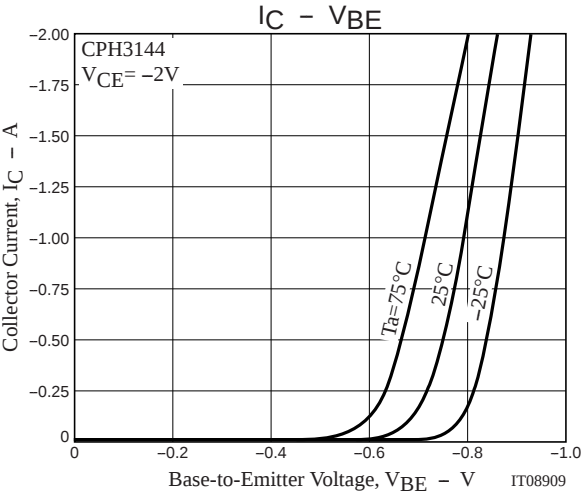
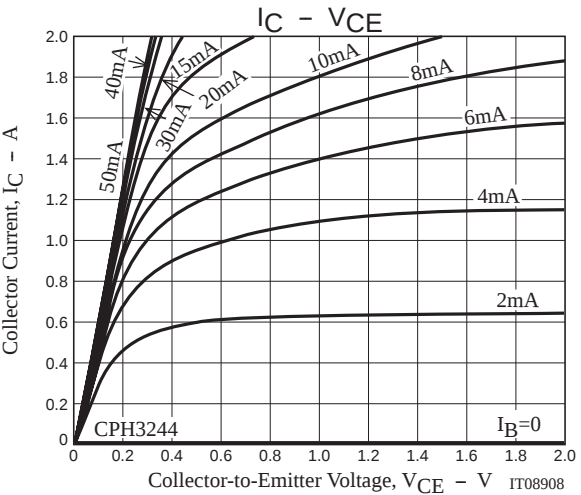
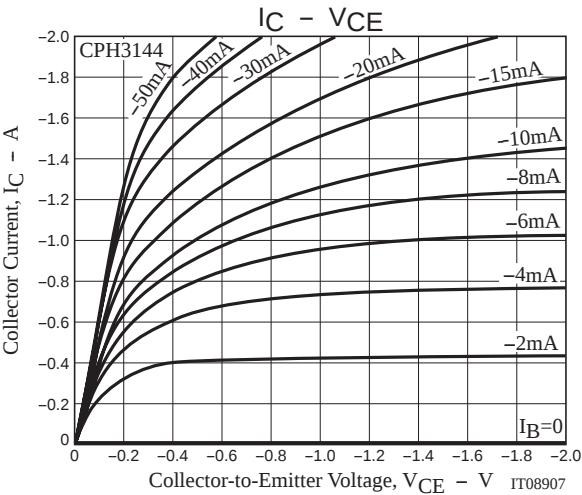
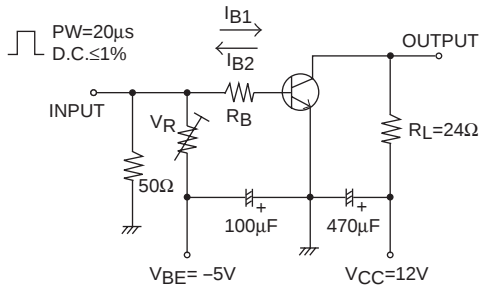
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)1.5A, I_B=(-)75mA$		(-170)160	(-260)240	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)1.5A, I_B=(-)75mA$		(-0.94	(-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-30)40			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		(45)40		ns
Storage Time	t_{stg}	See specified Test Circuit.		(200)350		ns
Fall Time	t_f	See specified Test Circuit.		(23)30		ns

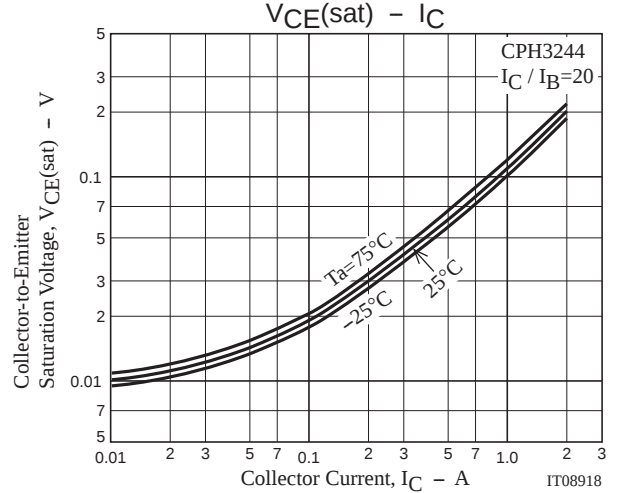
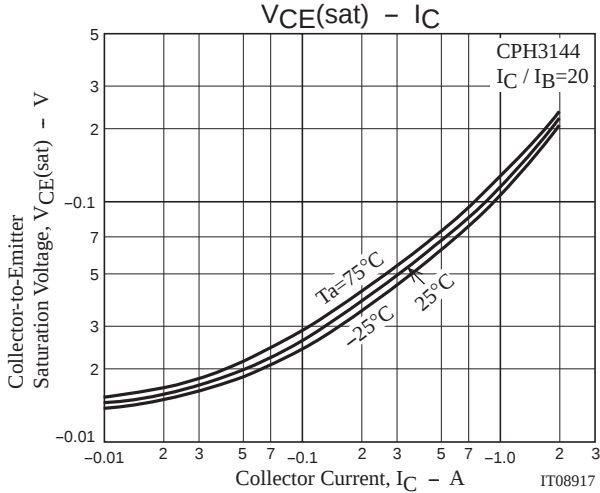
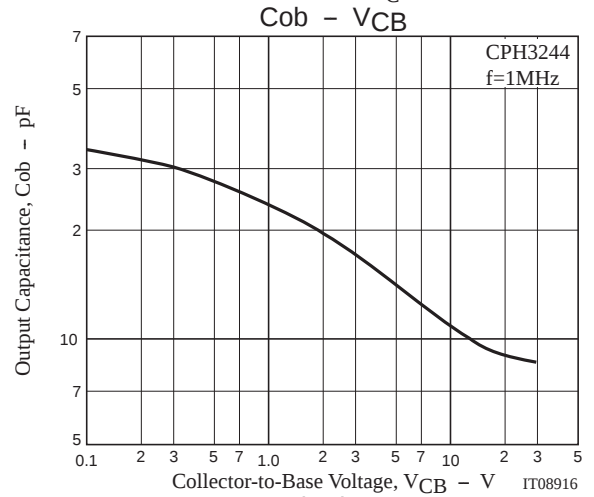
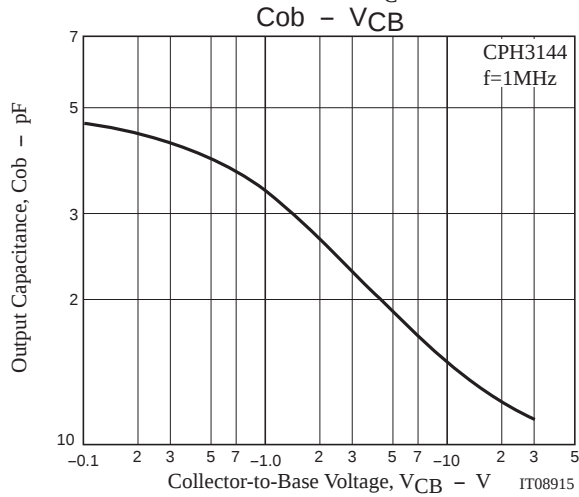
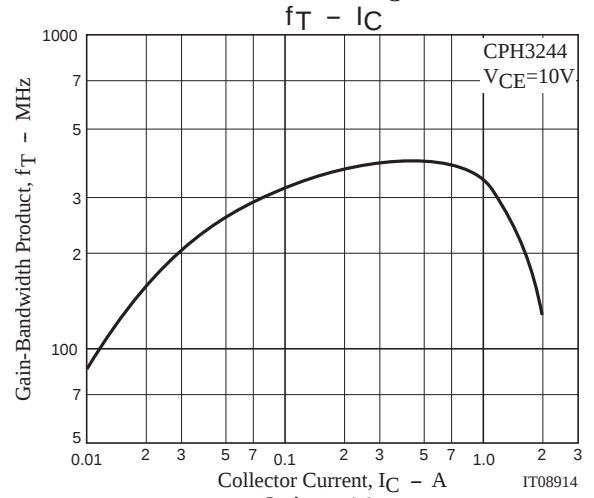
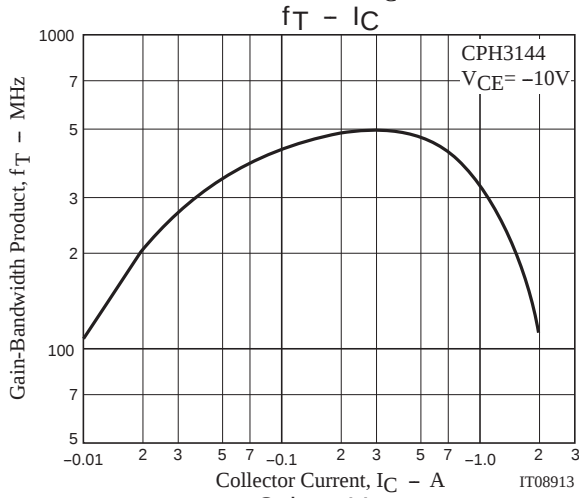
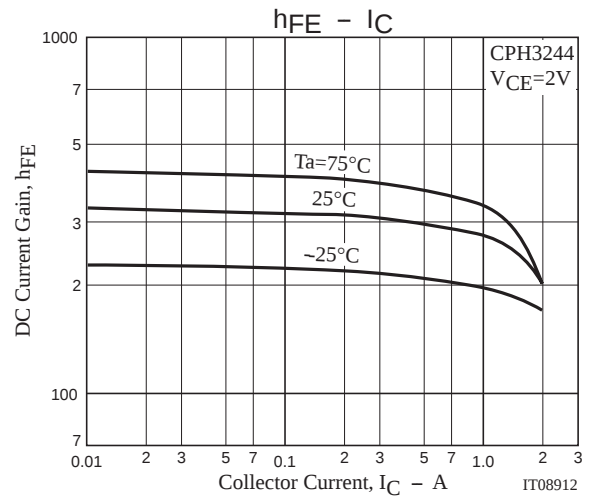
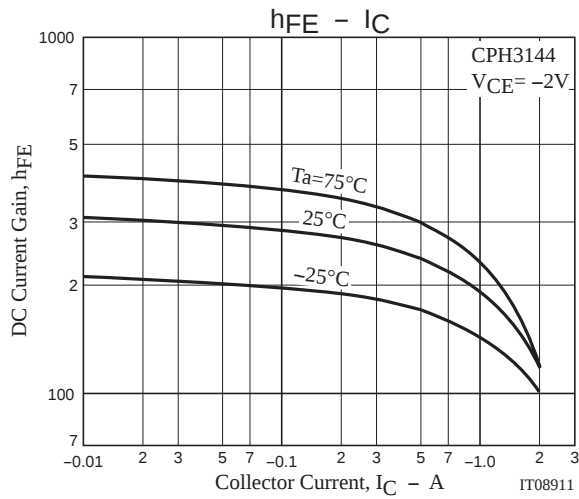
Package Dimensions

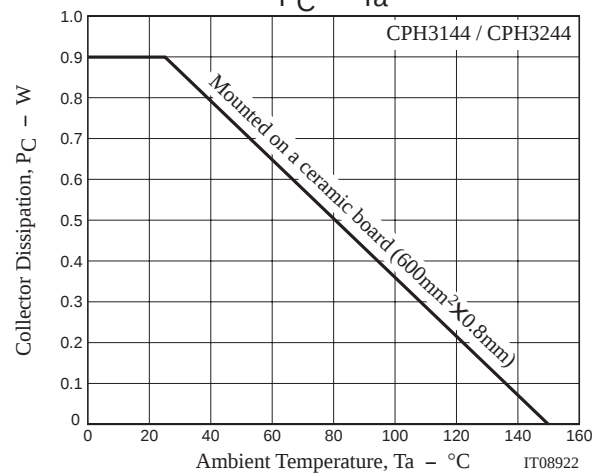
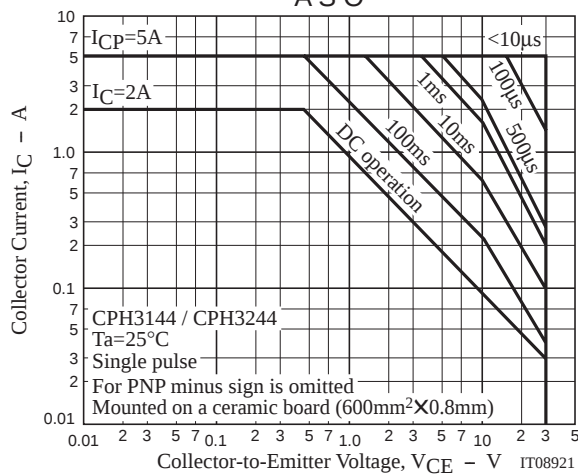
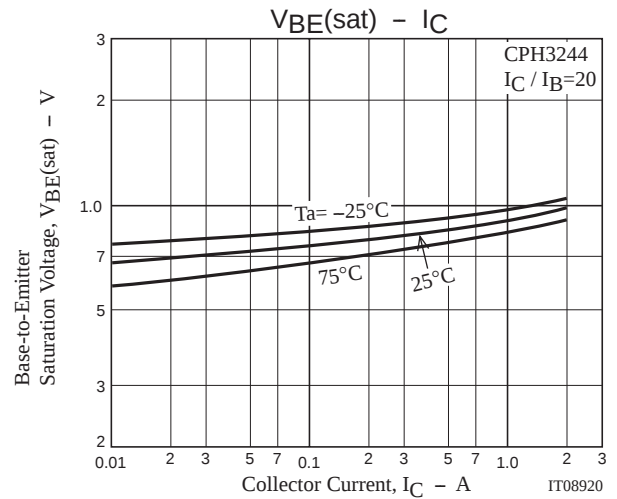
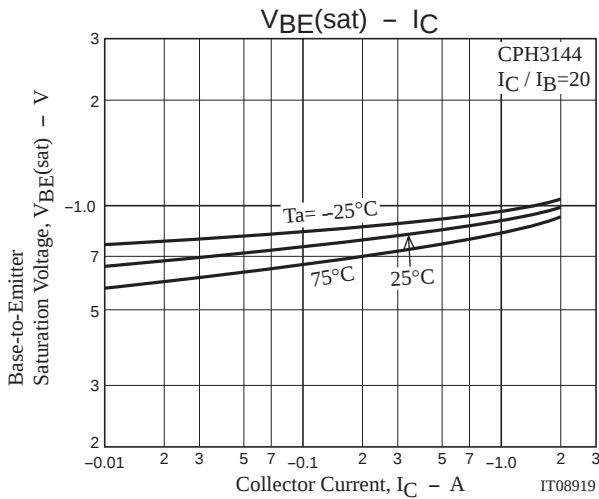
unit : mm
2150A



Switching Time Test Circuit







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